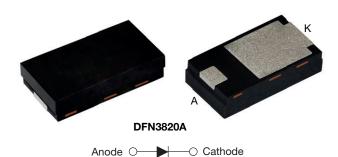
**Vishay Semiconductors** 

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# Ultrafast Rectifier, 5 A FRED Pt<sup>®</sup>



## LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	5 A			
V <sub>R</sub>	200 V			
V <sub>F</sub> at I <sub>F</sub>	0.72 V			
t <sub>rr</sub> (typ.)	15 ns			
I <sub>FSM</sub>	102 A			
T <sub>J</sub> max.	175 °C			
Package	DFN3820A			
Circuit configuration	Single			

## **FEATURES**

- · Very low profile typical height of 0.88 mm
- · Ideal for automated placement
- Wettable flanks allows easy inspection with AOI (automated optical inspection). No X-ray necessary
- Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- For PFC, CRM snubber operation
- AEC-Q101 gualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

## **TYPICAL APPLICATIONS**

For use in high frequency inverters, DC/DC converters, freewheeling diodes, clamping and snubber, polarity protection, dual voltage injector drivers, piezo drivers, ECU, Antilock Braking Systems (ABS), HID and LED lighting

### **MECHANICAL DATA**

Case: DFN3820A

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002, meets JESD 201 class 2 whisker test

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V <sub>RRM</sub>		200	V		
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>M</sub> = 154 °C	5	٨		
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_J = 25 \ ^{\circ}C$ , 10 ms sine pulse	102	A		
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	200	-	-	
	V	I <sub>F</sub> = 5 A	-	0.88	0.97	V
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 5 A, T <sub>J</sub> = 150 °C	-	0.72	0.79	
Poverse leekege ourrent	1	V <sub>R</sub> = V <sub>R</sub> rated	-	-	4	
Reverse leakage current	I <sub>R</sub>	$T_J = 150 \ ^{\circ}C, V_R = V_R \text{ rated}$	-	-	50	μA
Junction capacitance	CT	V <sub>R</sub> = 200 V	-	19	-	pF

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS MIN			MAX.	UNITS
		$I_{\rm F} = 0.5 \text{ A}, I_{\rm R} = 1 \text{ A}$	A, I <sub>rr</sub> = 0.25 A	-	15	25	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	12	-	ns
		T <sub>J</sub> = 125 °C		-	19	-	
Doold recovery ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	$I_F = 5 A$	-	4.1	-	A
Peak recovery current		T <sub>J</sub> = 125 °C	dI <sub>F</sub> /dt = 500 A/µs V <sub>R</sub> = 200 V	-	6.8	-	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	27	-	
		T <sub>J</sub> = 125 °C		-	69	-	nC

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C		
Thermal resistance, junction to mount	R <sub>thJM</sub> <sup>(1)</sup>		-	3.5	4.5			
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Device mounted on FR4 PCB, 2 oz. standard footprint	-	140	-	°C/W		
Weight			-	0.023	-	g		
Marking device		Case style DFN3820A	5H2					

#### Note

(1) Thermal resistance junction to mount follows JEDEC® 51-14 transient dual interface test method (TDIM)

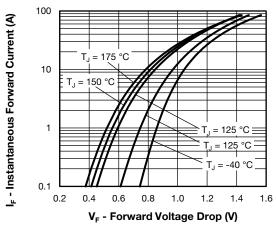


Fig. 1 - Typical Forward Voltage Drop Characteristics

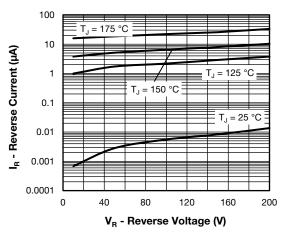


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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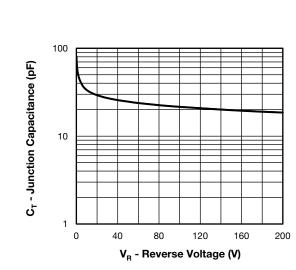


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

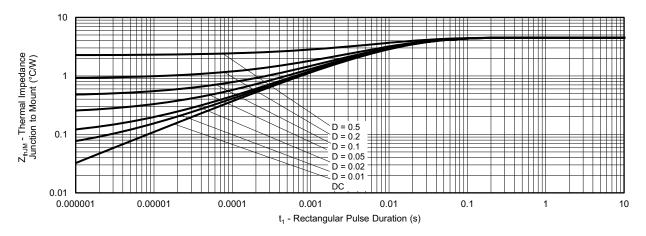
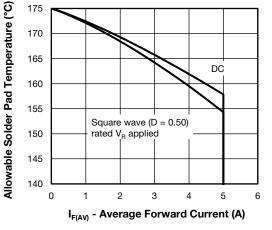
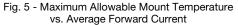


Fig. 4 - Maximum Transient Thermal Impedance, Junction to Mount



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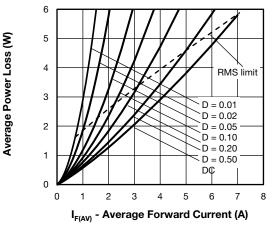


Fig. 6 - Forward Power Loss Characteristics

#### Note

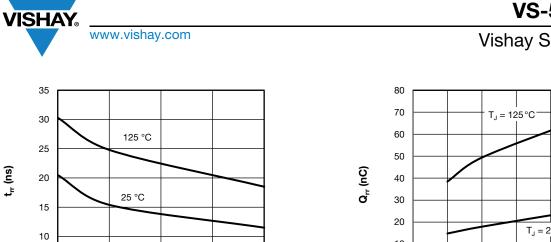
 $\begin{array}{l} \mbox{Formula used: } T_M = T_J - (Pd + Pd_{REV}) \ x \ R_{thJM}; \\ \mbox{Pd} = \mbox{forward power loss} = I_{F(AV)} \ x \ V_{FM} \ at \ (I_{F(AV)}/D) \ (see \ fig. \ 5); \\ \mbox{Pd}_{REV} = \ inverse \ power \ loss = V_{R1} \ x \ I_R \ (1 - D); \ I_R \ at \ V_{R1} = \ rated \ V_R \end{array}$ 

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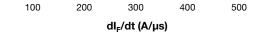
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Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

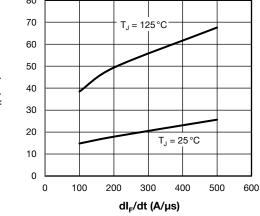
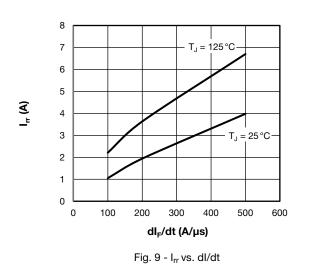


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt



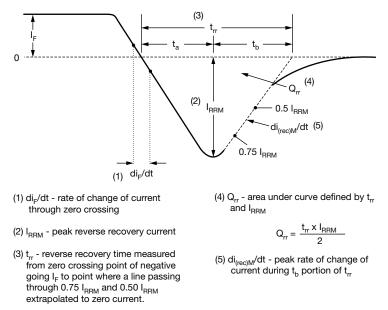


Fig. 10 - Reverse Recovery Waveform and Definitions

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## **ORDERING INFORMATION TABLE**

Device code	VS-	5	Е	A	н	02	н	М3
		2	3	4	5	6	7	8
	1 2 3	- Cur	rent rati	niconduo ng (5 = : iguration	5 A)	oduct		
	4 5	- A=	single o DFN38 cess typ	20A pac	ckage			
	7	- Voli - H =	tage coo AEC-Q	st recove de (02 = 101 qua en-free,	200 V) alified	complia	nt, and	termina

ORDERING INFORMATION (Example)							
PREFERRED P/N	PREFERRED PACKAGE CODE	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-5EAH02HM3/H	Н	3500	7" diameter plastic tape and reel				
VS-5EAH02HM3/I	Ι	14 000	13" diameter plastic tape and reel				

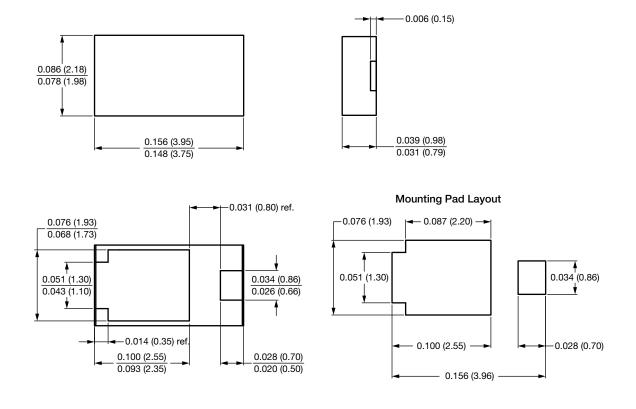
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?97066				
Part marking information	www.vishay.com/doc?97065				
Packaging information	www.vishay.com/doc?98488				
SPICE model	www.vishay.com/doc?97098				





DFN3820A, FRED Pt<sup>®</sup>

### **DIMENSIONS** in inches (millimeters)





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